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GaN on SiC HEMT Pulsed Power Transistor 500 W Peak, 960 to 1215 MHz, 128 µs Pulse, 10% Duty

Features

- GaN on SiC Depletion-Mode Transistor Technology
- Internally Matched
- Common-Source Configuration
- Broadband Class AB Operation
- RoHS* Compliant and 260 °C Reflow Compatible
- +50 V Typical Operation
- MTTF = 600 years (T_J < 200 $^{\circ}$ C)

Applications

- Civilian Air Traffic Control (ATC), L-Band Secondary Radar for IFF and Mode-S Avionics.
- Military radar for IFF and Data Links.

Description

The MAGX-000912-500L00 is a gold metalized matched Gallium Nitride (GaN) on Silicon Carbide (SiC) RF power transistor optimized for pulsed avionics and radar applications. Using state of the art wafer fabrication processes, these high provide high gain, performance transistors efficiency, bandwidth, and ruggedness over a wide bandwidth for today's demanding application needs. High breakdown voltages allow for reliable and stable operation under more extreme mismatch load conditions compared with older semiconductor technologies.

MAGX-000912-500L00



MAGX-000912-500L0S



Ordering Information¹

Part Number	Description
MAGX-000912-500L00	Flanged
MAGX-000912-500L0S	Flangeless
MAGX-A00912-500L00	960 - 1215 MHz Evaluation Board

1. When ordering the evaluation board, please indicate on sales order notes if it will be used for:

A. Standard Flange devices

B. Earless Flange devices

Typical RF Performance under standard operating conditions, Pout = 500 W (Peak)

Freq (MHz)	P _{IN} (W)	Gain (dB)	I _D (A)	Eff. (%)	RL (dB)	Droop (dB)	+1dB OD (W)	VSWR-S (3:1)	VSWR-T (5:1)
960	5.8	19.4	17.2	58.1	-6.4	0.4	563	S	Р
1025	4.9	20.1	16.2	61.4	-7.6	0.3	551	S	Р
1090	4.4	20.6	15.8	63.4	-9.6	0.3	560	S	Р
1150	4.4	20.6	17.0	58.7	-17.0	0.2	548	S	Р
1215	4.6	20.5	15.7	63.7	-12.6	0.2	558	S	Р

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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GaN on SiC HEMT Pulsed Power Transistor 500 W Peak, 960 to 1215 MHz, 128 µs Pulse, 10% Duty

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Electrical Specifications: Freq. = 960 - 1215 MHz, T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
RF Functional Tests						
Peak Input Power	-	P _{IN}	-	5.2	7.9	W
Power Gain		G _P	18	19.8	-	dB
Drain Efficiency		η_{D}	51	60	-	%
Pulse Droop		Droop	-	0.3	0.6	dB
Load Mismatch Stability		VSWR-S	-	3:1	-	-
Load Mismatch Tolerance		VSWR-T	-	5:1	-	-

Electrical Characteristics: T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
DC Characteristics						
Drain-Source Leakage Current	$V_{GS} = -8 V, V_{DS} = 175 V$	I _{DS}	-	1.0	30	mA
Gate Threshold Voltage	$V_{\text{DS}} = 5 \text{ V}, \ \text{I}_{\text{D}} = 75 \text{ mA}$	V _{GS (TH)}	-5	-3.1	-2	V
Forward Transconductance	$V_{DS} = 5 V, I_D = 17.5 mA$	G _M	12.5	19.2	-	S
Dynamic Characteristics						
Input Capacitance	Not applicable - Input matched	CISS	N/A	N/A	N/A	pF
Output Capacitance	$V_{DS} = 50 V$, $V_{GS} = -8 V$,	C _{OSS}	-	55	-	pF
Reverse Transfer Capacitance	Freq. = 1 MHz	C _{RSS}	-	5.5	-	pF

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Absolute Maximum Ratings^{2,3,4}

Parameter	Limit
Drain Voltage (V _{DD})	+65 V
Gate Voltage (V _{GG})	-8 to -2 V
Drain Current (I _{DD})	27.3 A
Input Power ⁵ (P _{IN})	P _{IN} (nominal) + 3 dB
Operating Junction Temperature ⁶	250 °C
Peak Pulsed Power Dissipation at 85 °C	875 W
Operating Temperature Range	-40 to +95 °C
Storage Temperature Range	-65 to +150 °C
ESD Maximum - Charged Device Model (CDM)	1300 V
ESD Maximum - Human Body Model (HBM)	4000 V

2. Exceeding any one or combination of these limits may cause permanent damage to this device.

3. MACOM does not recommend sustained operation near these survivability limits.

4. For saturated performance it is recommended that the sum of ($3 * V_{DD} + |V_{GG}|$) < 175 V.

5. Input Power Limit is +3 dB over nominal drive required to achieve $P_{OUT} = 500 \text{ W}$.

6. Operating junction temperature is measured with infrared (IR) microscope. Junction temperature directly affects a device's MTTF and should be kept as low as possible to maximize lifetime.

• MTTF = 5.3 x 10⁶ hours (T_J < 200 °C)

• MTTF = 6.8×10^4 hours (T_J < 250 °C)

Thermal Characteristics

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance	T_{C} = 70 °C, V_{DD} = 50 V, I_{DQ} = 400 mA, P_{OUT} = 500 W, Pulse Width = 128 µs, Duty Cycle = 10%	Θ _{JC}	0.2	°C/W

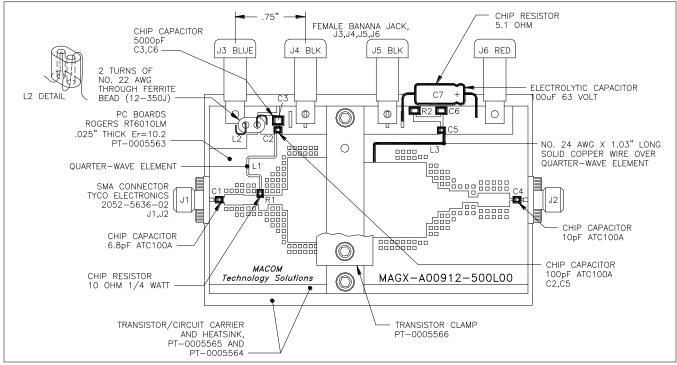
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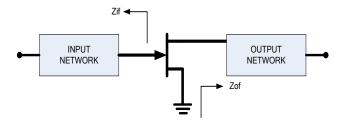
Test Fixture Assembly



Contact MACOM for additional circuit information.

Test Fixture Impedances

Freq. (MHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
960	1.1 - j1.1	1.8 + j0.8
1025	1.4 - j0.7	2.2 + j0.8
1090	1.7 - j0.5	2.4 + j0.6
1150	2.1 - j0.4	2.3 + j0.3
1215	2.4 - j0.7	1.9 + j0.2



Correct Device Sequencing

Turning the device ON

- 1. Set V_{GS} to the pinch-off (V_P), typically -5 V.
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until the I_{DS} current is reached.
- 4. Apply RF power to desired level.

Turning the device OFF

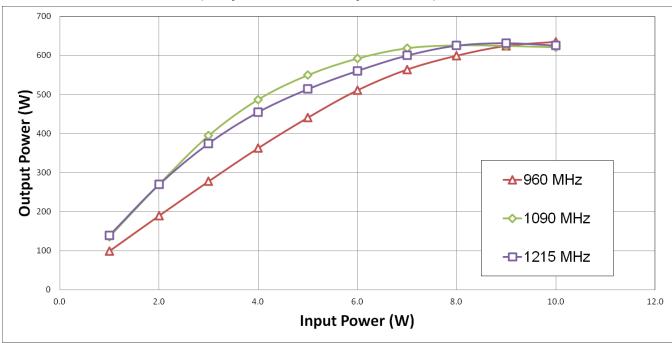
- 1. Turn the RF power off.
- 2. Decrease V_{GS} down to V_{P}
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS}

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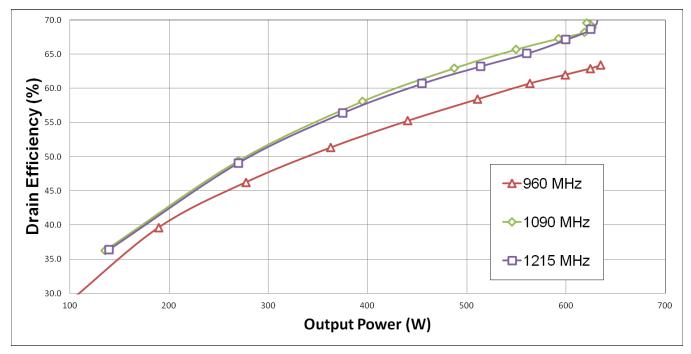
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RF Power Transfer Curve (Output Power Vs. Input Power)

RF Power Transfer Curve (Drain Efficiency Vs. Output Power)

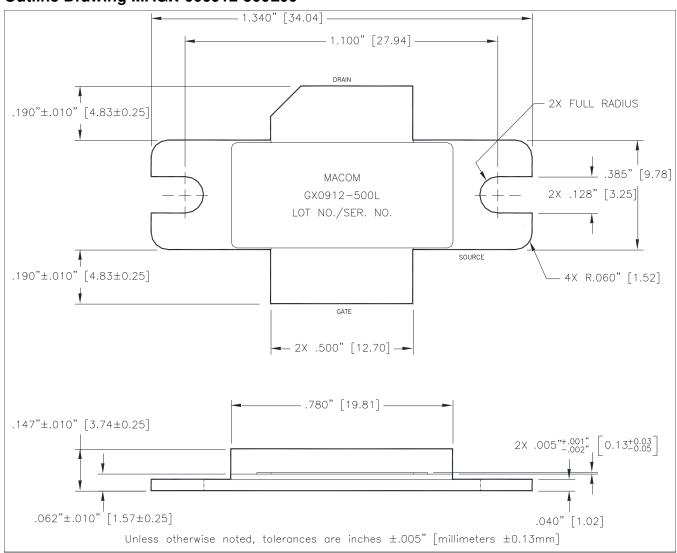


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Outline Drawing MAGX-000912-500L00⁺

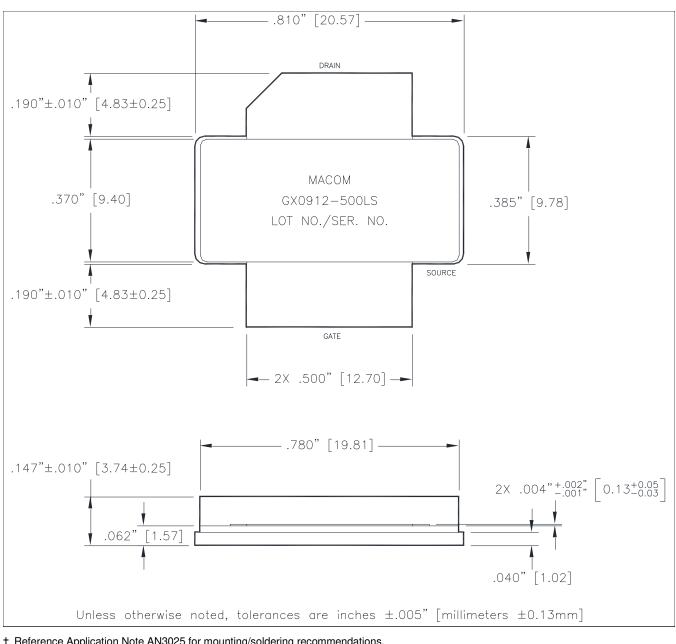


† Reference Application Note AN3025 for mounting/soldering recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is Ni/Au. Rev. V6





Outline Drawing MAGX-000912-500L0S[†]

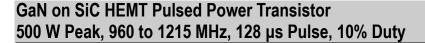


† Reference Application Note AN3025 for mounting/soldering recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is Ni/Au. МЛСОМ

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